

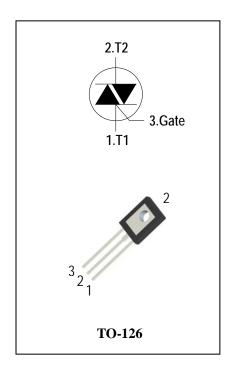
### 3 Quadrants Triacs

### **General Description**

High current density due to mesa technology .the ADS4C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers.

### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (I<sub>T(RMS)</sub>= 4A)
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant



### **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Depotitive Deals Off State Voltage	T: - 25°C	ADS4C60B	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS4C80B	800	V
I <sub>T(RMS)</sub>	R.M.S On-State Current	T <sub>C</sub> = 110 °C		4	Α
I <sub>TSM</sub>	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		25/27	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		3.1	A <sup>2</sup> s
-11/-14	Critical rate of rise of on-state	F = 120 Hz Tj = 125°C		50	Δ /
dl/dt	current	$I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$	50	A/µs	
I <sub>GM</sub>	Peak Gate Current	tp = 20 μs Tj = 125°C		2	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			0.5	W
P <sub>GM</sub>	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C

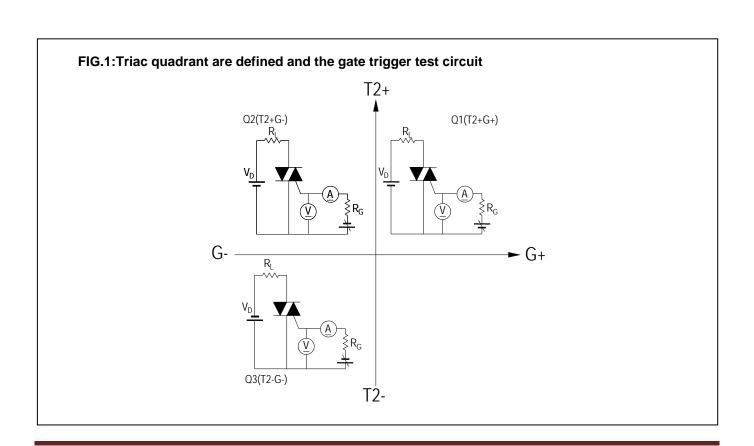






### **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS4C60B/80B			}	Unit	
					Т	S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C	N.4	5			uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 125$ °C	Max.	1			mA	
V <sub>TM</sub>	Peak On-S	tate Voltage	$I_{TM} = 5A$ , $t_p = 380 \ \mu s$	Max.	1.7			V	
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V		
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 220	Max.	1.3			V	
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	5	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	10	15	40	60	mA
	Q1-Q3		1 - 401	May	10	25	50	70	m 1
IL	Q2		iviax.	15	30	70	80	mA	
dV/dt	Critical Rate of Rise of Off-State $V_D = 2$ Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	20	40	400	1000	V/µs
(dV/dt)c	Rate of Change of Commutating  Current,		(dl/dt)c=-1.7A/ms Tj = 125°C	Min.	0.5	1	10	25	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)		Max.	3.0			°C/W		
R <sub>th(j-a)</sub>	Junction to ambient		Max.	100			°C/W		



# **ADV**

FIG.2: Maximum on-state power dissipation

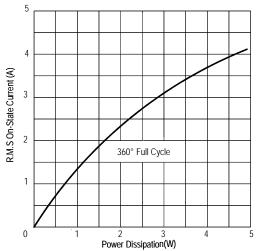


FIG.4: Maximum transient thermal impedance

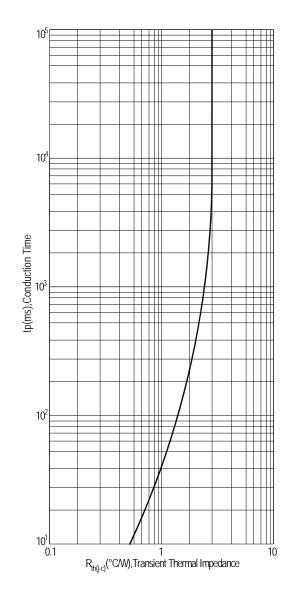


FIG.3: Typical RMS on-state current VS

Allowable case Temperature

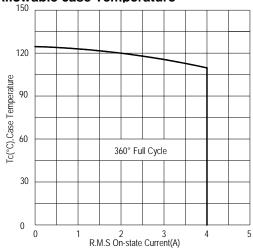


FIG.5: Rated surge on-state current (Non-Repetitive)

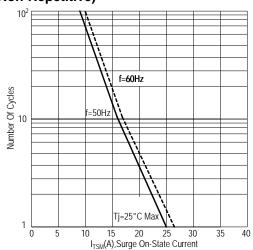


FIG.6: Gate trigger current VS Junction temperature

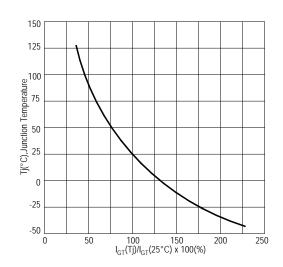




FIG.7:Holding current and Latching current VS Junction temperature

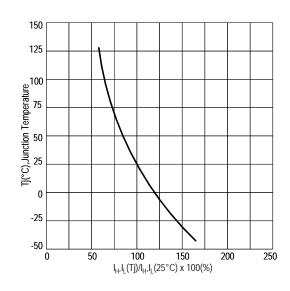


FIG.8: Gate trigger voltage VS Junction temperature

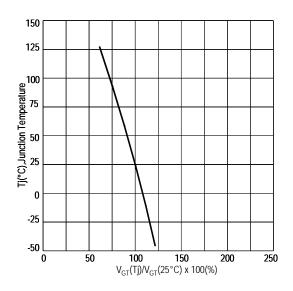
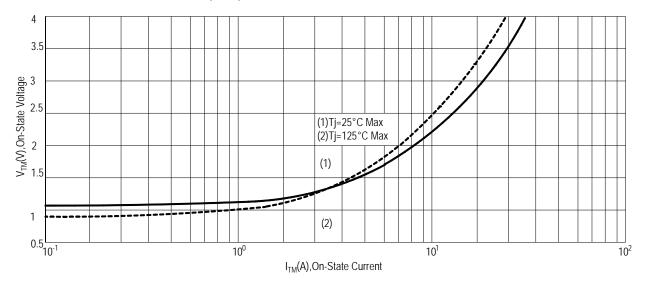


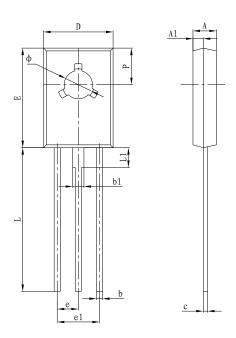
FIG.9: On-state characteristics(Max)



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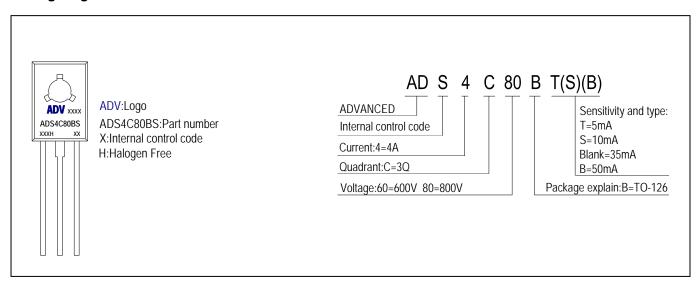


## PACKAGE MECHANICAL DATA TO-126 Package Dimension



Sy	Dimens	ions In	Dimensions In		
mb	Millimeters		Inches		
ol	Min	Max	Min	Max	
Α	2.500	2.900	0.098	0.114	
A1	1.100	1.500	0.043	0.059	
b	0.660	0.860	0.026	0.034	
b1	1.170	1.370	0.046	0.054	
С	0.450	0.600	0.018	0.024	
D	7.400	8.000	0.291	0.315	
Е	10.600	11.000	0.417	0.433	
е	2.290 TYP		0.090 TYP		
e1	4.480	4.680	0.176	0.184	
L	15.300	15.700	0.602	0.618	
L1	2.100	2.300	0.083	0.091	
Р	3.900	4.100	0.154	0.161	
Ф	3.000	3.200	0.118	0.126	

### **Making Diagram**



### **Ordering information**

Part number	Package	Marking	Packing	Quantity		
ADS4C60B#	TO-126	ADS4C60B#	Vinyl sack	500pcs		
ADS4C80B#	TO-126	ADS4C80B#	Vinyl sack	500pcs		
Note:# = Gate Trigger Current Sensitivity and type						



### ADS4C60B/80B

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